

Schottky Barrier Diode

30 V, 0.7 A, Low IR, Single CP

SB07-03C

Features

- Low Forward Voltage ($V_F max = 0.55 V$)
- Low Switching Noise
- Low Leakage Current and High Reliability Due to Highly Reliable Planar Structure
- Fast Reverse Recovery Rime (t_{rr} max = 10 ns)

Applications

• High Frequency Rectification (Switching Regulators, Converters,

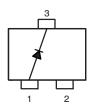
SPECIFICATIONS ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V _{RRM}	-	30	V
Nonrepetitive Peak Reverse Surge Voltage	V _{RSM}	-	35	>
Average Output Current	I _O	-	700	mA
Surge Forward Current	I _{FSM}	50 Hz sine wave, 1 cycle	5	Α
Junction Temperature	Tj	-	– 55 to +125	ů
Storage Temperature	T _{stg}	-	– 55 to +125	∘C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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ELECTRICAL CONNECTION





SC-59 / CP3 CASE 318BJ **ISSUE O**

MARKING DIAGRAM



XXX = Specific Device Code

= Date Code Μ = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
SB07-03C-TB-E	SC-59 / CP3 (Pb free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (at Ta = 25°C)

			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Voltage	VR	I _R = 300 μA	30	-	_	V
Forward Voltage	VF	I _F = 700 mA	-	-	0.55	V
Reverse Current	IR	V _R = 15 V	-	-	80	μА
Interterminal Capacitance	С	V _R = 10 V, f = 1 MHz	-	25	-	pF
Reverse Recovery Time	trr	I _F = I _R = 100 mA, See specified Test Circuit.	-	-	10	ns
Thermal Resistance	Rth _(j-a) 1		-	420	-	°C/W
	Rth _(j-a) 2	Mounted in Cu-foiled area of 16mm ² x 0.2mm on glass epoxy board	-	330	-	°C/W

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

trr Test Circuit

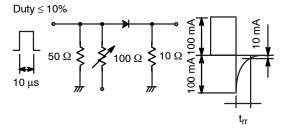


Figure 1. t_{rr} Test Circuit

SB07-03C

TYPICAL CHARACTERISTICS

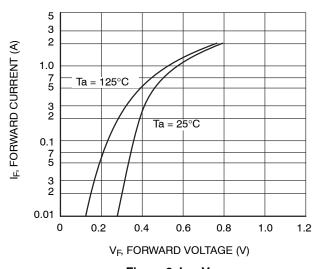


Figure 2. I_F – V_F

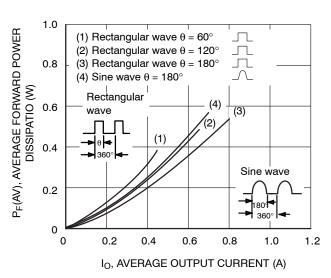


Figure 4. P_F(AV) - I_O

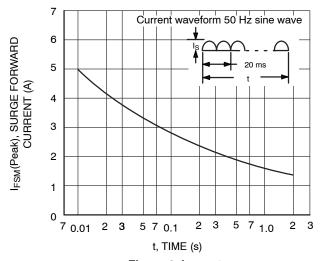


Figure 6. I_{FSM} - t

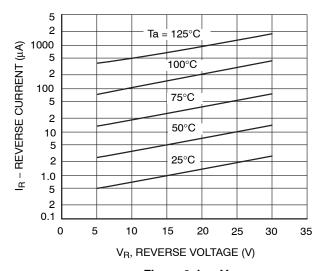


Figure 3. I_R - V_R

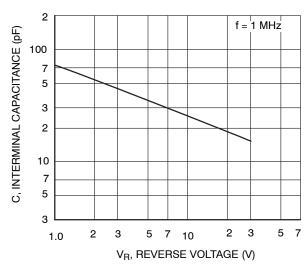


Figure 5. C - V_R

MECHANICAL CASE OUTLINE

3X L

зх b

⊕ 0.10 M C A

C SEATING PLANE

Α

E1

е





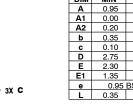
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DATE 09 JAN 2015

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER SIDE.
 4. DIMENSIONS D AND E1 ARE MEASURED AT THE OUTERMOST
- EXTREME OF THE PLASTIC BODY.
 DIMENSIONS 6 AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 AND 0.20 FROM THE TIP.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.95	1.35	
A1	0.00	0.10	
A2	0.20	0.40	
b	0.35	0.50	
С	0.10	0.20	
D	2.75	3.05	
E	2.30 2.70		
E1	1.35 1.65		
е	0.95 BSC		
_	0.35	0.75	



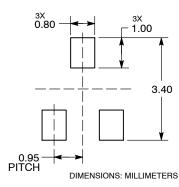
END VIEW

RECOMMENDED **SOLDERING FOOTPRINT***

SIDE VIEW

Δ1

TOP VIEW



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM



XXX = Specific Device Code

Μ = Date Code

= Pb-Free Package

(Note: Microdot may be in either location) *This information is generic. Please refer to

device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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